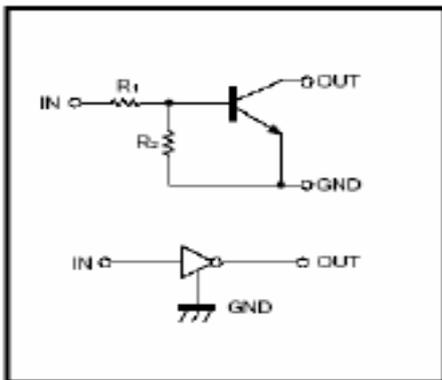


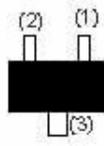
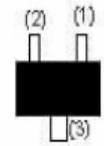
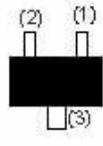
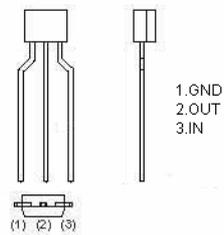
RoHS Compliant Product  
A suffix of "-C" specifies halogen & lead-free

## FEATURES

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- Only the on/off conditions need to be set for operation, making device design easy.

## EQUIVALENT CIRCUIT



<p><b>DTC144EE (SOT-523)</b></p>  <p>1.IN 2.GND 3.OUT</p> <p>Abbreviated symbol : 26</p>	<p><b>DTC144EUA (SOT-323)</b></p>  <p>1.IN 2.GND 3.OUT</p> <p>Abbreviated symbol : 26</p>
<p><b>DTC144EM (SOT-723)</b></p>  <p>1.IN 2.GND 3.OUT</p> <p>Abbreviated symbol : 26</p>	<p><b>DTC144ECA (SOT-23)</b></p>  <p>1.IN 2.GND 3.OUT</p> <p>Abbreviated symbol : 26</p>
<p><b>DTA144ESA (TO-92S)</b></p>  <p>1.GND 2.OUT 3.IN</p>	

## ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise noted)

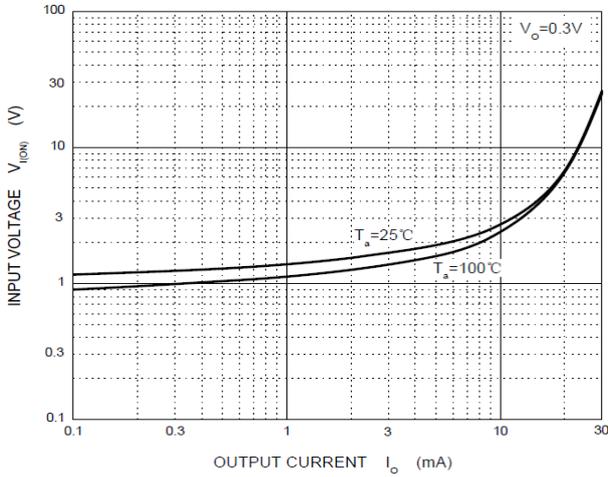
Parameter	Symbol	Limits (DTC144E□)					Unit
		M	E	UA	CA	SA	
Collector-Base Voltage	V <sub>CC</sub>	50					V
Input voltage	V <sub>IN</sub>	-10~40					V
Output current	I <sub>O</sub>	30					mA
	I <sub>C(MAX)</sub>	100					
Power dissipation	P <sub>D</sub>	100	150	200	300	mW	
Junction & Storage temperature	T <sub>J</sub> , T <sub>STG</sub>	150, -55~150					°C

**ELECTRICAL CHARACTERISTICS** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

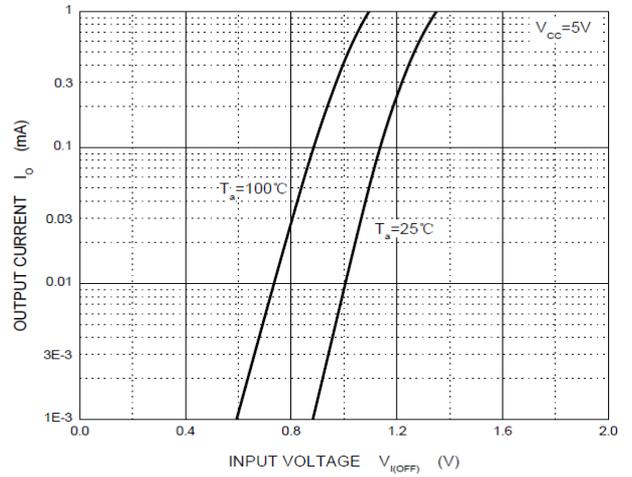
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Input voltage	$V_{I(\text{off})}$	0.5	-	-	V	$V_{CC}=5\text{V}$ , $I_O=100\mu\text{A}$
	$V_{I(\text{on})}$	-	-	3		$V_O=0.3\text{V}$ , $I_O=2\text{mA}$
Output voltage	$V_{O(\text{on})}$	-	-	0.3	V	$I_O/I_I=10\text{mA}/0.5\text{mA}$
Input current	$I_I$	-	-	0.18	mA	$V_I=5\text{V}$
Output current	$I_{O(\text{off})}$	-	-	0.5	$\mu\text{A}$	$V_{CC}=50\text{V}$ , $V_I=0$
DC current gain	$G_I$	68	-	-		$V_O=5\text{V}$ , $I_O=5\text{mA}$
Input resistance	$R_1$	32.9	47	61.1	K $\Omega$	
Resistance ratio	$R_2/R_1$	0.8	1	1.2		
Transition frequency	$f_T$	-	250	-	MHz	$V_O=10\text{V}$ , $I_O=5\text{mA}$ , $f=100\text{MHz}$

**CHARACTERISTIC CURVES**

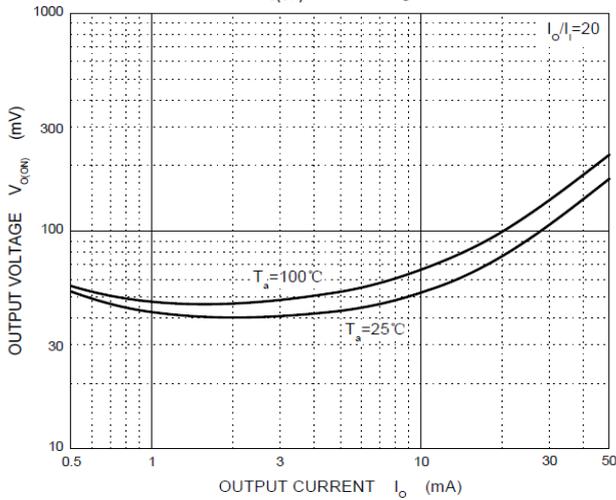
**ON Characteristics**



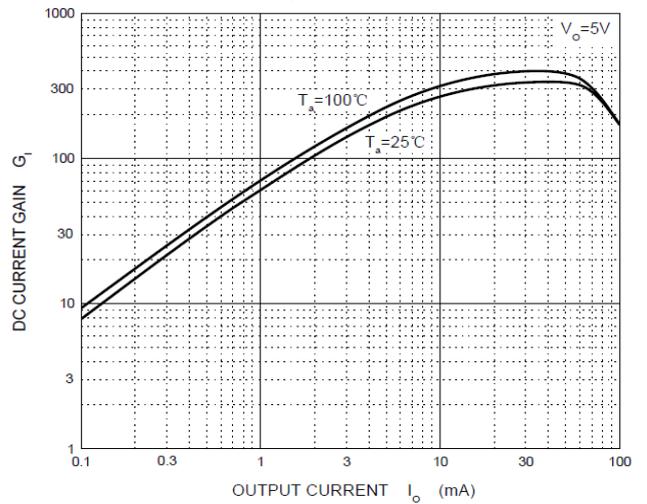
**OFF Characteristics**



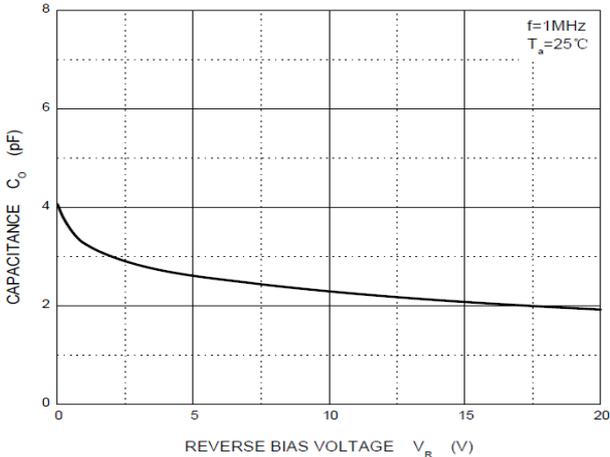
**$V_{(ON)}$  —  $I_o$**



**$G_I$  —  $I_o$**



**$C_o$  —  $V_R$**



**$P_D$  —  $T_a$**

